NSN 5961-01-117-5658

Transistor - Page 1 of 1

Demilitarization:

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-117-5658 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Overall Diameter:** 0.285 inches **End Application:** An/apx-76b 80249 fscm **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 28.0 collector to emitter voltage, dc and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 1.00 milliamperes zero-gate-voltage source current minor **Power Rating Per Characteristic:** 4.3 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 80249-911374 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 flange and 2 pin Shelf Life: N/a **Unit Of Measure:**